

LINEAR INTEGRATED CIRCUITS

DESCRIPTION

The $\mu A741$ is a high performance operational amplifier with high open loop gain, internal compensation, high common mode range and exceptional temperature stability. The $\mu A741$ is short-circuit protected and allows for nulling of offset voltage.

FEATURES

- INTERNAL FREQUENCY COMPENSATION
- SHORT CIRCUIT PROTECTION
- OFFSET VOLTAGE NULL CAPABILITY
- EXCELLENT TEMPERATURE STABILITY
- HIGH INPUT VOLTAGE RANGE
- NO LATCH-UP

ABSOLUTE MAXIMUM RATINGS

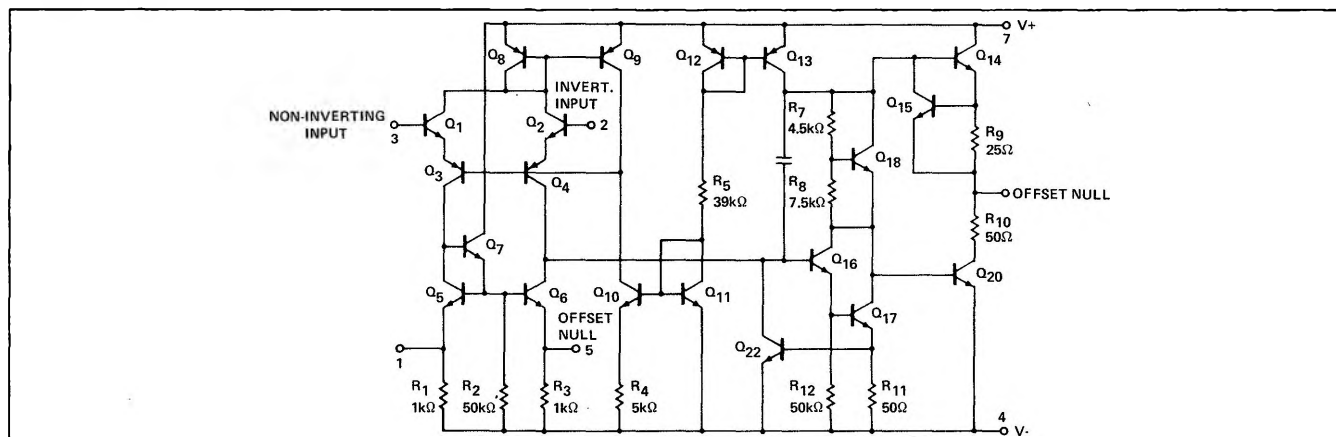
	$\mu A741C$	$\mu A741$
Supply Voltage	$\pm 18V$	$\pm 22V$
Internal Power		
Dissipation (Note 1)	500mW	500mW
Differential Input Voltage	$\pm 30V$	$\pm 30V$
Input Voltage (Note 2)	$\pm 15V$	$\pm 15V$
Voltage between Offset Null and V^-	$\pm 0.5V$	$\pm 0.5V$
Operating Temperature		
Range	$0^\circ C$ to $+70^\circ C$	$-55^\circ C$ to $+125^\circ C$
Storage Temperature		
Range	$-65^\circ C$ to $+150^\circ C$	$-65^\circ C$ to $+150^\circ C$

Lead Temperature		
(Solder, 60 sec)	$300^\circ C$	$300^\circ C$
Output Short Circuit	Indefinite	Indefinite
Duration (Note 3)		

Notes

1. Rating applies for case temperatures to $125^\circ C$; derate linearly at $6.5mW/^\circ C$ for ambient temperatures above $+75^\circ C$.
2. For supply voltages less than $\pm 15V$, the absolute maximum input voltage is equal to the supply voltage.
3. Short circuit may be to ground or either supply. Rating applies to $+125^\circ C$ case temperature or $+75^\circ C$ ambient temperature.

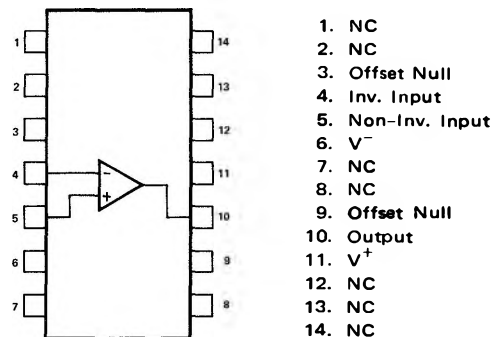
EQUIVALENT CIRCUIT



PIN CONFIGURATIONS

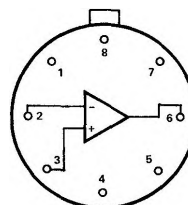
A PACKAGE

(Top View)



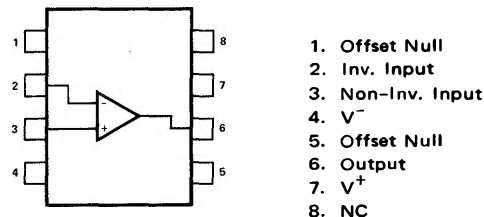
ORDER PART NO. $\mu A741CA$

T PACKAGE



ORDER PART NOS. $\mu A741T/\mu A741CT$

V PACKAGE



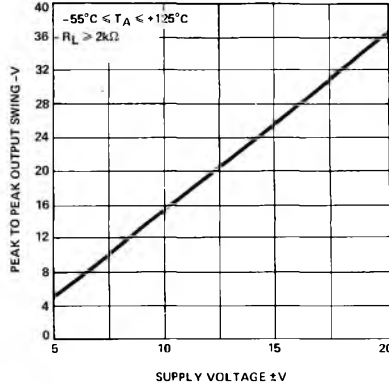
ORDER PART NO. $\mu A741CV$

SIGNETICS ■ μ A741 — HIGH PERFORMANCE OPERATIONAL AMPLIFIER
ELECTRICAL CHARACTERISTICS ($V_S = \pm 15V$, $T_A = 25^\circ C$ unless otherwise specified)

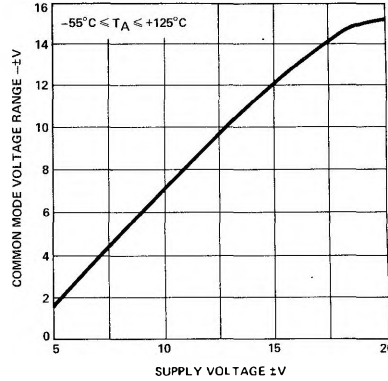
PARAMETER	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
μA741C					
Input Offset Voltage		2.0	6.0	mV	$R_S \leq 10k\Omega$
Input Offset Current		20	200	nA	
Input Bias Current		80	500	nA	
Input Resistance	0.3	2.0		M Ω	
Input Capacitance		1.4		pF	
Offset Voltage Adjustment Range		± 15		mV	
Input Voltage Range	± 12	± 13		V	
Common Mode Rejection Ratio	70	90		dB	$R_S \leq 10k\Omega$
Supply Voltage Rejection Ratio		10	150	$\mu V/V$	$R_S \leq 10k\Omega$
Large-Signal Voltage Gain	20,000	200,000			$R_L \geq 2k\Omega$, $V_{out} = \pm 10V$
Output Voltage Swing	± 12 ± 10	± 14 ± 13		V V	$R_L \geq 10k\Omega$ $R_L \geq 2k\Omega$
Output Resistance		75		Ω	
Output Short-Circuit Current		25		mA	
Supply Current		1.4	2.8	mA	
Power Consumption		50	85	mW	
Transient Response (unity gain)					$V_{in} = 20mV$, $R_L = 2k\Omega$, $C_L \leq 100pF$
Risettime		0.3		μs	
Overshoot		5.0		%	
Slew Rate		0.5		V/ μs	$R_L \geq 2k\Omega$
The following specifications apply for $0^\circ C \leq T_A \leq +70^\circ C$					
Input Offset Voltage			7.5	mV	
Input Offset Current			300	nA	
Input Bias Current			800	nA	
Large-Signal Voltage Gain	15,000				$R_L \geq 2k\Omega$, $V_{out} = \pm 10V$
Output Voltage Swing	± 10	± 13		V	$R_L \geq 2k\Omega$
μA741					
Input Offset Voltage		1.0	5.0	mV	$R_S \leq 10k\Omega$
Input Offset Current		10	200	nA	
Input Bias Current		80	500	nA	
Input Resistance	0.3	2.0		M Ω	
Input Capacitance		1.4		pF	
Offset Voltage Adjustment Range		± 15		mV	
Large-Signal Voltage Gain	50,000	200,000			$R_L \geq 2k\Omega$, $V_{out} = \pm 10V$
Output Resistance		75		Ω	
Output Short Circuit Current		25		mA	
Supply Current		1.4	2.8	mA	
Power Consumption		50	85	mW	
Transient Response (unity gain)					$V_{in} = 20mV$, $R_L = 2k\Omega$, $C_L \leq 100pF$
Risettime		0.3		μs	
Overshoot		5.0		%	
Slew Rate		0.5		V/ μs	$R_L \geq 2k\Omega$
The following specifications apply for $-55^\circ C \leq T_A \leq +125^\circ C$					
Input Offset Voltage		1.0	6.0	mV	$R_S \leq 10k\Omega$
Input Offset Current		7.0	200	nA	$T_A = +125^\circ C$
		20	500	nA	$T_A = -55^\circ C$
Input Bias Current		0.03	0.5	μA	$T_A = +125^\circ C$
		0.3	1.5	μA	$T_A = -55^\circ C$
Input Voltage Range	± 12	± 13		V	
Common Mode Rejection Ratio	70	90		dB	$R_S \leq 10k\Omega$
Supply Voltage Rejection Ratio		10	150	$\mu V/V$	$R_S \leq 10k\Omega$
Large-Signal Voltage Gain	25,000				$R_L \geq 2k\Omega$, $V_{out} = \pm 10V$
Output Voltage Swing	± 12 ± 10	± 14 ± 13		V V	$R_L \geq 10k\Omega$ $R_L \geq 2k\Omega$
Supply Current		1.5	2.5	mA	$T_A = +125^\circ C$
		2.0	3.3	mA	$T_A = -55^\circ C$
Power Consumption		45	75	mW	$T_A = +125^\circ C$
		45	100	mW	$T_A = -55^\circ C$

TYPICAL CHARACTERISTIC CURVES

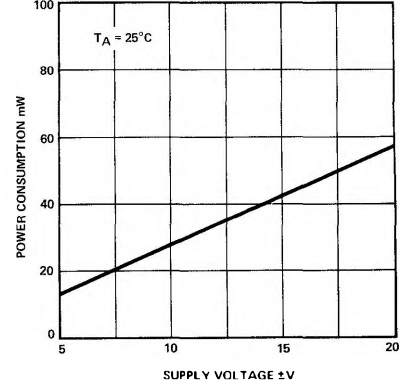
OUTPUT VOLTAGE SWING
AS A FUNCTION OF
SUPPLY VOLTAGE



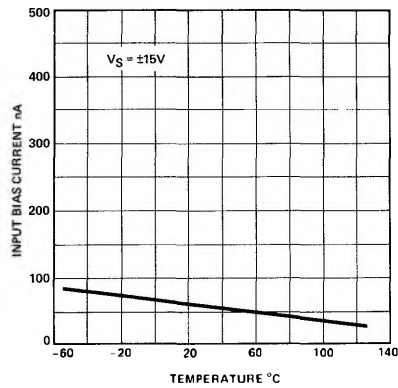
INPUT COMMON MODE
VOLTAGE RANGE AS
A FUNCTION OF SUPPLY VOLTAGE



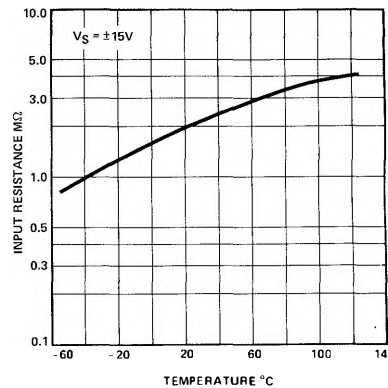
POWER CONSUMPTION
AS A FUNCTION OF
SUPPLY VOLTAGE



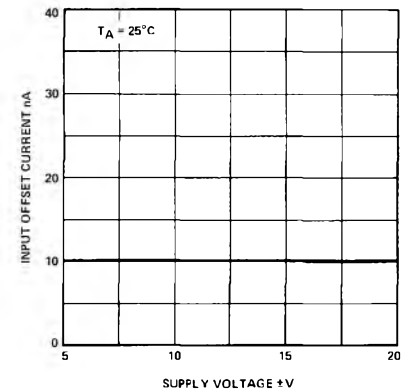
INPUT BIAS CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATURE



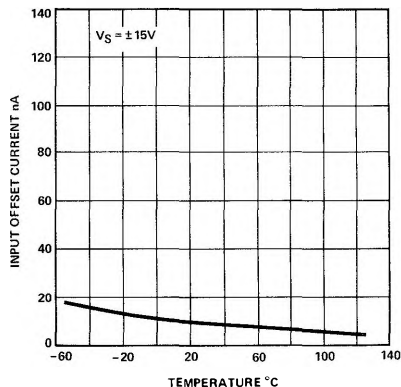
INPUT RESISTANCE
AS A FUNCTION OF
AMBIENT TEMPERATURE



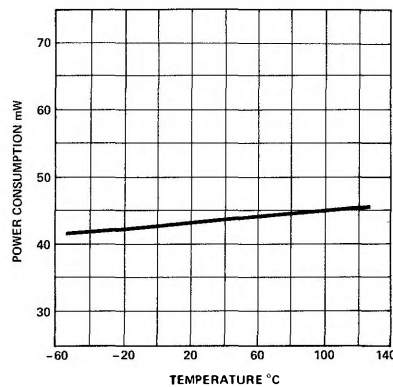
INPUT OFFSET CURRENT
AS A FUNCTION OF
SUPPLY VOLTAGE



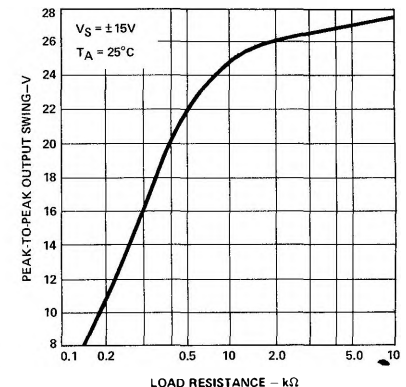
INPUT OFFSET CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATURE



POWER CONSUMPTION
AS A FUNCTION OF
AMBIENT TEMPERATURE

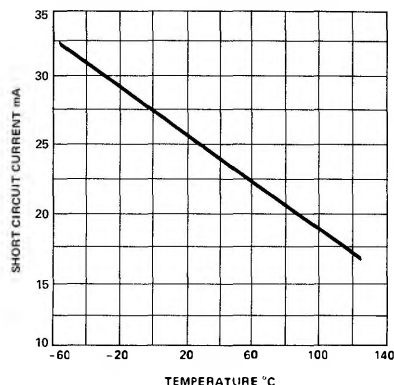


OUTPUT VOLTAGE SWING
AS A FUNCTION OF
LOAD RESISTANCE

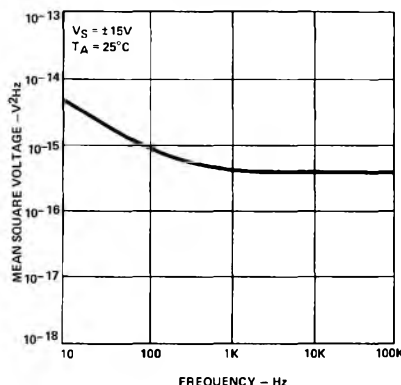


TYPICAL CHARACTERISTIC CURVES (Cont'd.)

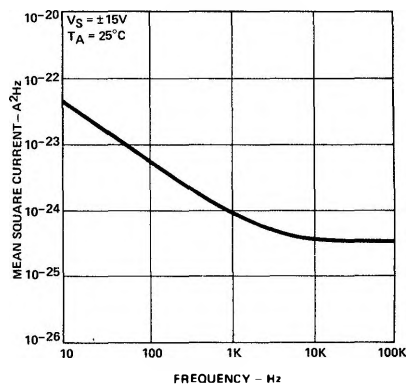
OUTPUT SHORT-CIRCUIT CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATURE



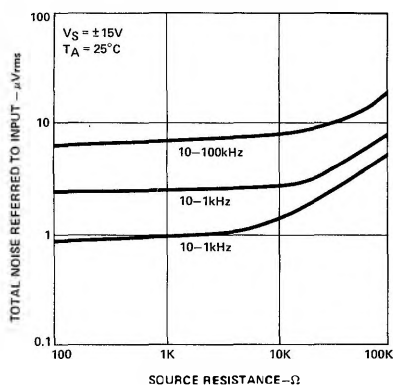
INPUT NOISE VOLTAGE
AS A FUNCTION OF
FREQUENCY



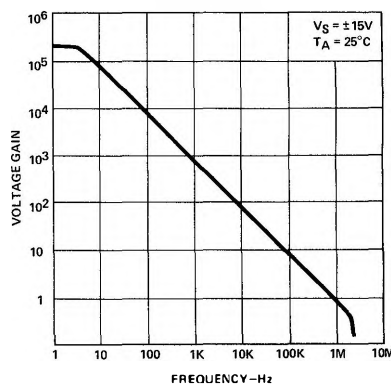
INPUT NOISE CURRENT
AS A FUNCTION OF
FREQUENCY



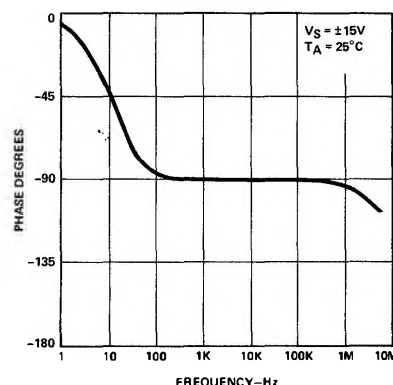
BROADBAND NOISE FOR
VARIOUS BANDWIDTHS



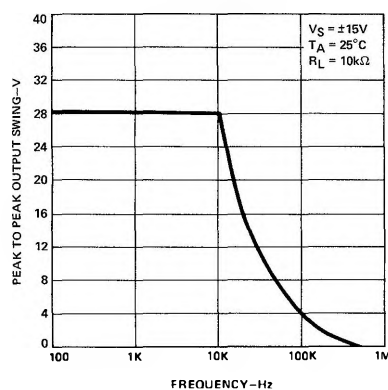
OPEN LOOP VOLTAGE GAIN
AS A FUNCTION OF
FREQUENCY



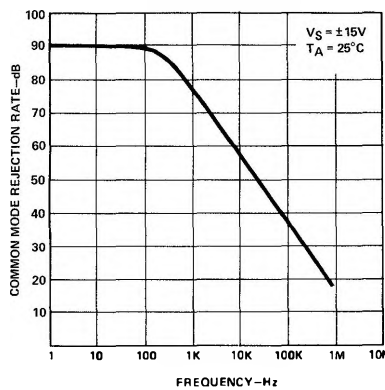
OPEN LOOP PHASE RESPONSE
AS A FUNCTION OF
FREQUENCY



OUTPUT VOLTAGE SWING
AS A FUNCTION OF
FREQUENCY



COMMON MODE REJECTION
RATIO AS A FUNCTION OF
FREQUENCY



TRANSIENT RESPONSE

